## CLAIM AMENDMENTS

1. (Currently Amended) A package for Optical an optical semiconductor device comprising;

a stem having an under surface, an upper surface, a mount to be mounted, with an optical semiconductor device, on the upper surface, at least one or more through holes hole penetrating from the upper surface to the under surface, and

a lead terminal for signal supply penetrating one of said the through holes so as to be and insulated by an insulator from the stem, wherein said the upper surface has an earth conductor adjacent to the lead terminal for signal supply projected projecting from the upper surface.

- 2. (Currently Amended) The package for Optical an optical semiconductor devices according to claim 15, wherein said the earth conductor is enclosing encloses at least part of said the lead terminal for signal supply projected projecting from the upper surface.
- 3. (Currently Amended) The package for Optical an optical semiconductor device according to claim 25, wherein said the earth conductor is surrounding a range of surrounds at least 150 degrees or more centering on the around a center axis of said the lead terminal for signal supply projected projecting from the upper surface.
- 4. (Currently Amended) The package for Optical an optical semiconductor device according to claim 152 wherein said the earth conductor is formed with said includes the mount monolithically.
- 5. (Currently Amended) The package for Optical an optical semiconductor device according to claim 15, wherein said the earth conductor overlaps with said the insulator.
- 6. (Currently Amended) The package for Optical an optical semiconductor device according to claim 1; wherein including a dielectric member is placed located between said the earth conductor and said the lead terminal for signal supply.
- 7. (Currently Amended) The package for Optical an optical semiconductor device according to claim 1; wherein including earth electrode terminals are arranged in both on

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opposite sides of said the terminal for signal supply projected projecting from the under surface of the above-mentioned stem.

- 8. (Currently Amended) The package for Optical an optical semiconductor device according to claim 15, wherein said the earth electrode terminals are monolithically integrated with said the stem.
- 9. (Currently Amended) The package for Optical an optical semiconductor device according to claim 15 further comprising a second lead terminal for signal supply pairing with said the lead terminal for signal supply.
- 10. (Currently Amended) The package for Optical an optical semiconductor device according to claim 15, wherein said the earth conductor is formed with said includes the mount monolithically and said the mount is attached on said to the stem so that said the earth conductor overlaps with said the insulator.
- 11. (Currently Amended) The package for Optical an optical semiconductor device according to claim 1;, wherein said the mount and said the stem are produced by press processing, respectively.
- 12. (Currently Amended) The package for Optical an optical semiconductor device according to claim 10½, wherein a distance between said the earth conductors conductor and said the lead terminal for signal supply is set so that provides a characteristic impedance of a transmission line constituted with said by the lead terminal for signal supply projected projecting from the upper surface of said the stem is set to of no more than 60 ohms or less.
- 13. (Currently Amended) The package for Optical an optical semiconductor device according to claim 105, wherein a distance between said the earth conductors conductor and said the lead terminal for signal supply is no more than 0.175mm or less.
- 14. (Currently Amended) The package for Optical an optical semiconductor device according to claim 10; further comprising a guide for positioning said the mount on the upper surface of said the stem.

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- 15. (Currently Amended) The package for Optical an optical semiconductor device according to claim 10; 12, wherein a tip portion of said the lead terminal for signal supply is deformed so that said the characteristic impedance of said transmission line become small is reduced.
- 16. (Currently Amended) The package for Optical an optical semiconductor device according to claim 15; wherein said lead terminal for signal supply is formed in has a cylinder shape and said the tip portion is deformed by crushing the cylinder shape into a flat portion.
- 17. (Currently Amended) The package for Optical an optical semiconductor device according to claim 15; wherein a face of the earth conductor surrounding said the lead terminal is crooked along with said-deformed the tip portion of said lead terminal for signal supply.
- 18. (Currently Amended) The package for Optical an optical semiconductor device according to claim 10½ wherein said the mount has a step at a corner thereof in the lap portion of said earth conductor and said overlapping the insulator so that said the earth conductor is does not directly contact the direct above mentioned insulator.
- 19. (Currently Amended) The package for Optical an optical semiconductor device according to claim 10½, wherein said the mount is placed located on the upper surface of said the stem with and including a plinth between them the mount and the stem in the lap portion of said the earth conductor and said overlapping the insulator so that said the earth conductor is does not directly contact the direct above-mentioned insulator.
- 20. (Currently Amended) The package for Optical an optical semiconductor device according to claim 10½, wherein said the mount has a corner made in with a circumference circumferential shape in the lap portion of said the earth conductor and said overlapping the insulator so that said the earth conductor is does not directly contact the direct abovementioned insulator.

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